NSN 5961-01-356-4279

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-356-4279 **Inclosure Material:** Ceramic **Overall Length:** Between 0.790 inches and 0.810 inches **Overall Height:** 0.185 inches **Overall Width:** 0.600 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 25.0 breakdown voltage, collector-to-emitter, base open and 3.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 0.27 amperes source cutoff current **Power Rating Per Characteristic:** 5.8 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Nuclear hardness critical item. Caution: contains beryllium oxide; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 ribbon and 1 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:** No